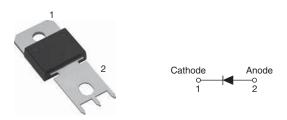
VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 85 A

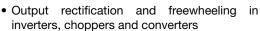


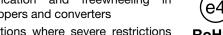
PowerTab[®]

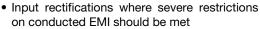
PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	85 A			
V_{R}	1200 V			
V _F at I _F	1.36 V			
I _{FSM}	1250 A			
t _{rr}	95 ns			
T _J max.	150 °C			
Diode variation	Single die			
Snap factor	0.5			

FEATURES

- · Glass passivated pallet chip junction
- 150 °C max. operating junction temperature









- · Screw mounting only
- Designed and qualified according to JEDEC®-JESD 47
- AEC-Q101 qualified
- PowerTab® package
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdeness connectivity for use in high current environments.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rect. conduction 50 % duty cycle at T _C = 85 °C	85	A	
I _{F(RMS)}		160	A	
V _{RRM}		1200	V	
I _{FSM}		1250	Α	
V _F	100 A, T _J = 25 °C	1.4	V	
t _{rr}	1 A, - 100 A/μs	95	ns	
T _J	Range	-40 to +150	°C	

VOLTAGE RATINGS			
TYPE NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-85EPF12	1200	1300	15

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 85 °C, 180° conduction half sine wave	85		
Maximum peak one cycle non-repetitive surge current I _{FSM}	1	10 ms sine pulse, rated V _{RRM} applied	1100	Α	
	IFSM	10 ms sine pulse, no voltage reapplied	1250		
Maximum I ² t for fusing I ² t	12+	10 ms sine pulse, rated V _{RRM} applied	5000	A ² s	
	ı-t	10 ms sine pulse, no voltage reapplied	7000	A-S	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A ² √s	

VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	85 A, T _J = 25 °C		1.36	V
Forward slope resistance	r _t	T _J = 150 °C		4.03	mΩ
Threshold voltage	V _{F(TO)}			0.87	V
Maximum rayoraa laakaga aurrant	1	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C		15	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t _{rr}	I _F at 85 A _{pk}	480	ns	I _{FM} t
Reverse recovery current	I _{rr}	25 A/µs	7.1	А	
Reverse recovery charge	Q _{rr}	25 °C	2.1	μC	dir/ dt Q
Snap factor	S		0.5		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistar junction to case	nce,	R _{thJC}	DC operation	0.35	
Maximum thermal resistar junction to ambient	nce,	R _{thJA}		40	°C/W
Typical thermal resistance case to heatsink) ,	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	OZ.
Manustina taurus	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking device			Case style PowerTab®	85EF	PF12

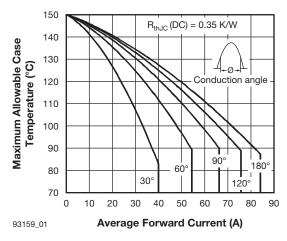


Fig. 1 - Current Rating Characteristics

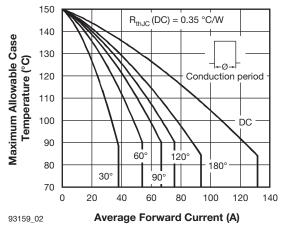


Fig. 2 - Current Rating Characteristics

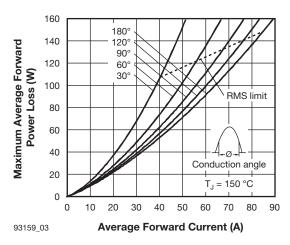


Fig. 3 - Forward Power Loss Characteristics

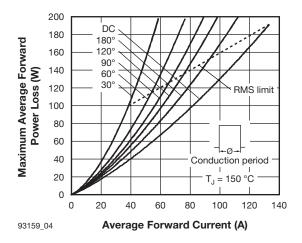


Fig. 4 - Forward Power Loss Characteristics

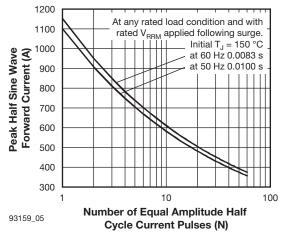


Fig. 5 - Maximum Non-Repetitive Surge Current

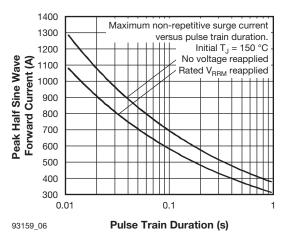
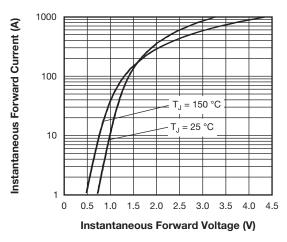


Fig. 6 - Maximum Non-Repetitive Surge Current



www.vishay.com

Fig. 7 - Forward Voltage Drop Characteristics

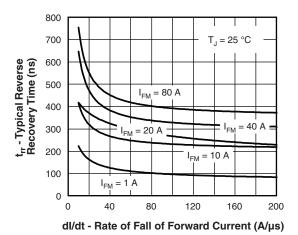


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

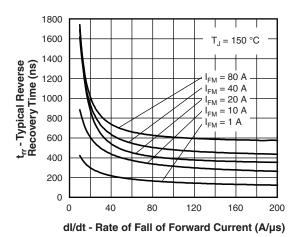


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

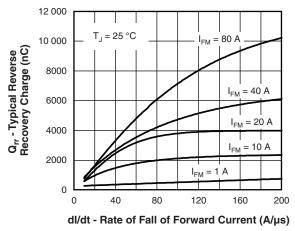


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

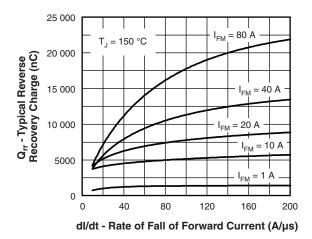
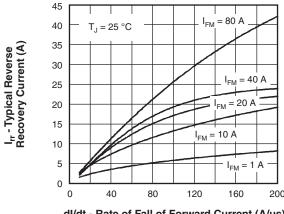


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

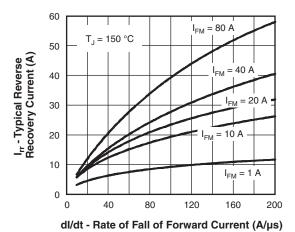


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

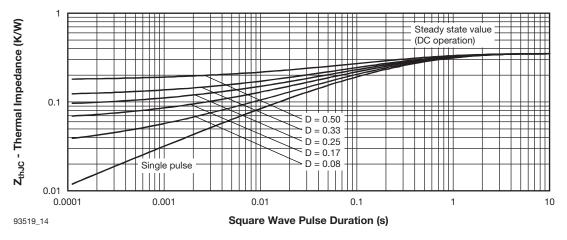


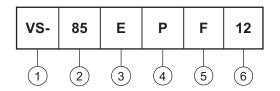
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - Circuit configuration:

E = Single diode

4 - Package:

P = TO-247AC

5 - Type of silicon:

F = Fast recovery

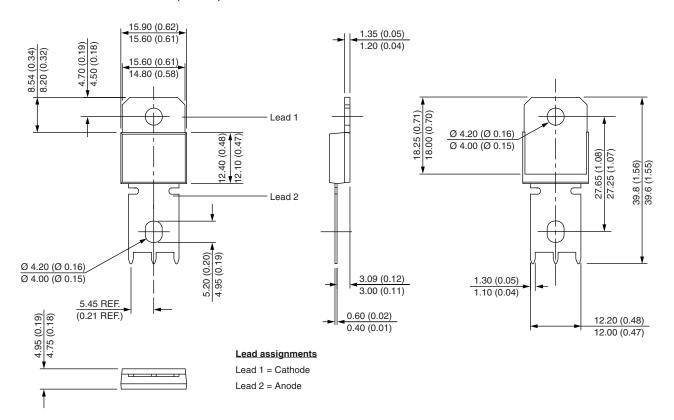
6 - Voltage code x 100 = V_{RRM} (12 = 1200 V)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95240		
Part marking information	www.vishay.com/doc?95370		
Application note	www.vishay.com/doc?95179		



PowerTab[®]

DIMENSIONS in millimeters (inches)





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Vishay

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